**TENTATIVE** 

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# TC7WH14FU, TC7WH14FK

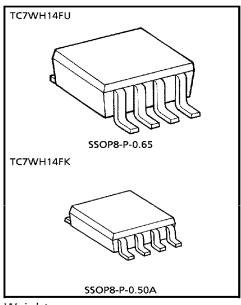
# (UNDER DEVELOPMENT)

# TRIPLE SCHMITT INVERTER

The TC7WH14 is an advanced high speed CMOS SCHMITT INVERTER fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. Pin configuration and function are the same as the TC7SH14 but the inputs have hysteresis and with its schmitt trigger function, the TC7SH14 can be used as a line receivers which will receive slow input signals. An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

#### **FEATURES**

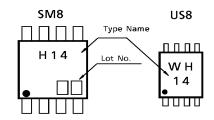
- ..... t<sub>pd</sub> = 5.5ns (Typ.) at V<sub>CC</sub> = 5V High Speed Low Power Dissipation ......  $I_{CC} = 2\mu A$  (Max.) at  $Ta = 25^{\circ}C$
- High Noise Immunity ..... V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (Min.)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays ····· t<sub>pLH</sub>≒t<sub>pHL</sub>
- Wide Operating Voltage Range ···  $V_{CC}$  (opr) = 2~5.5V

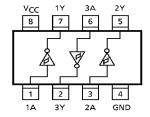


Weight SSOP8-P-0.65 : 0.02g (Typ.) SSOP8-P-0.50A : 0.01g (Typ.)

#### MARKING

# PIN ASSIGNMENT (TOP VIEW)





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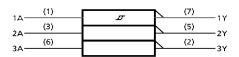
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# **MAXIMUM RATINGS** (Ta = $25^{\circ}$ C)

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Supply Voltage Range	VCC	- 0.5~7.0	V	
DC Input Voltage	VIN	-0.5~7.0	٧	
DC Output Voltage	Vout	-0.5~V <sub>CC</sub> +0.5	V	
Input Diode Current	ΙΚ	<b>– 20</b>	mA	
Output Diode Current	<sup>ј</sup> ок	± 20	mA	
DC Output Current	lout	± 25	mA	
DC V <sub>CC</sub> /Ground Current	lcc	± 50	mA	
Bayyan Dissipation	D-	300 (SM8)	mW	
Power Dissipation	PD	200 (US8)	11177	
Storage Temperature	T <sub>stg</sub>	<b>- 65∼150</b>	°C	
Lead Temperature (10 s)	TL	260	°C	

#### LOGIC DIAGRAM



# TRUTH TABLE

А	Υ
L	Н
Н	L

#### **RECOMMENDED OPERATING CONDITIONS**

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Supply Voltage	Vcc	2.0~5.5	V	
Input Voltage	VIN	0~5.5	V	
Output Voltage	Vout	0~V <sub>CC</sub>	V	
Operating Temperature	T <sub>opr</sub>	<b>- 40∼8</b> 5	°C	
Input Rise and Fall Time	dt/dv	$0 \sim 100 \text{ (V}_{CC} = 3.3 \pm 0.3 \text{V)}$	ns/V	
input Rise and Fail Time	at/av	$0\sim20 \ (V_{CC}=5\pm0.5V)$	] 1157 V	

# DC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	TEST CONDITION		Vcc	Ta = 25°C			Ta = -4	UNIT	
CHARACTERISTIC STIMBOL TEST CO		ONDITION	(V)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT	
Positive				3.0	_	_	2.20	_	2.20	
Threshold	V <sub>P</sub>			4.5	_	_	3.15	_	3.15	V
Voltage				5.5	_	_	3.85	_	3.85	
Negative				3.0	0.90	_	_	0.90	_	
Threshold	٧N			4.5	1.35	_	_	1.35	_	V
Voltage				6.0	1.65	_	_	1.65	_	
Hysteresis				3.0	0.30	_	1.20	0.30	1.20	
Voltage	VΗ			4.5	0.40	_	1.40	0.40	1.40	V
Voltage				5.5	0.50	_	1.60	0.50	1.60	
	Vон	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OH</sub> = -50μA	2.0	1.9	2.0	_	1.9	_	
High-Level				3.0	2.9	3.0	_	2.9	_	
Output Voltage				4.5	4.4	4.5	_	4.4	_	V
Output Voltage			$I_{OH} = -4mA$	3.0	2.58	_	_	2.48		
			$I_{OH} = -8mA$	4.5	3.94	_	_	3.80	_	
	VOL	V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OL</sub> = 50μA	2.0	_	0.0	0.1	_	0.1	v
Low-Level				3.0	_	0.0	0.1	_	0.1	
Output Voltage				4.5	_	0.0	0.1	_	0.1	
			$I_{OL} = 4mA$	3.0	_	_	0.36		0.44	
			$I_{OL} = 8mA$	4.5	_	_	0.36	_	0.44	.44
Input Leakage Current	IN	V <sub>IN</sub> = 5.5V or GND		0~ 5.5	_	_	± 0.1	_	± 1.0	μΑ
Quiescent Supply Current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	2.0	_	20.0	μΑ

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AC ELECTRICAL CHARACTERISTICS (Inpu
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CHARACTERISTIC SYMBO		TEST C	ONDITION		Ta = 25°C			Ta = −40~85°C		UNIT
CHARACTERISTIC STIVIBO	STIVIBOL		V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
Propagation Delay t <sub>pLH</sub> Time t <sub>pHL</sub>			3.3 ± 0.3	15	_	8.3	12.8	1.0	15.0	
	tpLH			50	_	10.8	16.3	1.0	18.5	
	tpHL	_	5.0 ± 0.5	15	_	5.5	8.6	1.0	10.0	ns
			3.0 ± 0.3	50	_	7.0	10.6	1.0	12.0	
Input Capacitance	CIN		_		1	4	10	_	10	рF
Power Dissipation	Power Dissipation CpD (Note 1)					21				рF
Capacitance	C <sub>PD</sub>	(NOTE 1)			_	41	_	_	_	ÞΓ

(Note 1): C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

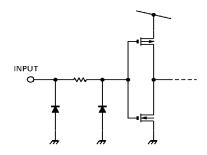
Average operating current can be obtained by the equation:

 $ICC (opr) = CPD \cdot VCC \cdot fIN + ICC$ 

#### **NOISE CHARACTERISTICS** (Ta = 25°C, Input $t_r = t_f = 3ns$ )

CHARACTERISTIC	SYMBOL	TEST CONDITION	V <sub>CC</sub> (V)	TYP.	LIMIT	UNIT
Quiet Output Maximum Dynamic V <sub>OL</sub>	V <sub>OLP</sub>	C <sub>L</sub> = 50pF	5.0	0.3	0.8	٧
Quiet Output Minimum Dynamic V <sub>OL</sub>	VOLV	C <sub>L</sub> = 50pF	5.0	- 0.3	- 0.8	٧
Minimum High Level Dynamic Input Voltage	VIHD	C <sub>L</sub> = 50pF	5.0	_	3.5	٧
Maximum Low Level Dynamic Input Voltage	V <sub>ILD</sub>	C <sub>L</sub> = 50pF	5.0		1.5	V

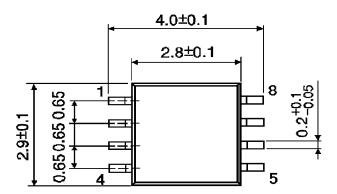
# INPUT EQUIVALENT CIRCUIT

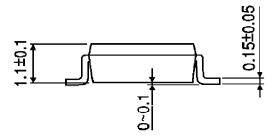


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# OUTLINE DRAWING SSOP8-P-0.65

Unit: mm

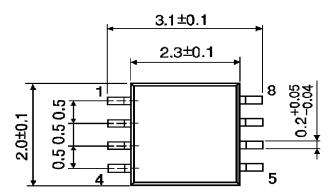


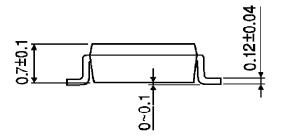


Weight: 0.02g (Typ.)

# OUTLINE DRAWING SSOP8-P-0.50A

Unit: mm





Weight: 0.01g (Typ.)